

	Type	Ref #	Hits	Search Text	DBs	Time Stamp	Comments	Error Definition
1	IS&R	S6	1	("6670202").PN.	US-PGPUB; USPAT; USOCR	2004/12/01 17:52		
2	IS&R	S7	1	("5,770,471").PN.	US-PGPUB; USPAT; USOCR	2004/12/01 17:37		
3	BRS	S8	0	("6670202").URPN.	USPAT	2004/12/01 17:41		
4	BRS	S9	2	("5592501" "5770471").PN.	US-PGPUB; USPAT; USOCR	2004/12/01 17:41		
5	BRS	S10	2	("5592501" "5770471").PN. OR ("6670202").URPN.	US-PGPUB; USPAT; USOCR	2004/12/01 17:41		
6	BRS	S11	19	("4825262" "4859060" "5022745" "5142414" "5291502" "5331658" "5339326" "5381434" "5491710" "5561523" "5561680" "5629951" "5646729" "5739945" "5771253" "5818862" "5825796" "5879961" "5949801").PN.	US-PGPUB; USPAT; USOCR	2004/12/02 09:44		
7	BRS	S12	23	("5450427" "5666225").PN. OR ("5949801").URPN.	US-PGPUB; USPAT; USOCR	2004/12/02 09:44		
8	BRS	S13	17	("4825262" "4859060" "5022745" "5142414" "5291502" "5331658" "5339326" "5491710" "5561523" "5561680" "5629951" "5646729" "5739945" "5771253" "5818862" "5825796" "5879961").PN.	US-PGPUB; USPAT; USOCR	2004/12/02 09:44		
9	BRS	S14	21	("5949801").URPN.	USPAT	2004/12/02 09:44		
10	BRS	S15	32	("4825262" "4859060" "5022745" "5142414" "5291502" "5331658" "5339326" "5491710" "5561523" "5561680" "5629951" "5646729" "5739945" "5771253" "5818862" "5825796" "5879961").PN. OR ("6438149").URPN.	US-PGPUB; USPAT; USOCR	2004/12/02 09:44		
11	BRS	S16	165	(semiconductor near3 laser) and clad\$5 and active and etch\$5 and (impur\$5 near3 diffus\$4) and ridge	USPAT	2004/12/02 10:01		
12	BRS	S17	270	(semiconductor near3 laser) and clad\$5 and active and etch\$5 and (impur\$5 near3 diffus\$4) and (ridge\$5 or mesa)	USPAT	2004/12/02 10:01		
13	BRS	S18	148	(semiconductor near3 laser) and clad\$5 and active and etch\$5 and (impur\$5 near3 diffus\$4) and ridge and "372"/\$	USPAT	2004/12/02 10:02		
14	BRS	S19	115	(semiconductor near3 laser) and clad\$5 and active and etch\$5 and (impur\$5 near3 diffus\$4) and ridge and "372"/\$.ccls.	USPAT	2004/12/02 10:03		
15	BRS	S20	8	(semiconductor near3 laser) and clad\$5 and active and etch\$5 and (impur\$5 near3 diffus\$4) and ridge and "372"/\$.ccls. and (light near3 emit\$6 near3 surface)	USPAT	2004/12/02 10:07		

16	BRS	S23	7	semiconductor near3 laser) and clad\$5 and active and etch\$5 and (impur\$5 near3 diffus\$4) and ridge and "372"/\$.ccls. and (light near3 emit\$6 near3 surface)	US-PGPUB; USOCR: EPO; JPO; DERWENT	2004/12/02 10:05		
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	Type	Ref #	Hits	Search Text	DBs	Time Stamp	Comments	Error Definition
17	BRS	S21	13	(semiconductor near3 laser) and clad\$5 and active and etch\$5 and (impur\$5 near3 diffus\$4) and ridge and (light near3 emit\$6 near3 surface)	USPAT	2004/12/02 10:05		
18	BRS	S24	1	(semiconductor near3 laser) and clad\$5 and active and etch\$5 and (impur\$5 near3 diffus\$4) with (light near3 emit\$6 near3 surface)) and ridge	USPAT	2004/12/02 10:08		
19	BRS	S25	1	(semiconductor near3 laser) and clad\$5 and active and etch\$5 and (impur\$5 near3 diffus\$4) same (light near3 emit\$6 near3 surface)) and ridge	USPAT	2004/12/02 10:08		
20	BRS	S22	13	(semiconductor near3 laser) and clad\$5 and active and etch\$5 and (impur\$5 near3 diffus\$4) and ridge and (light near3 emit\$6 near3 surface)	US-PGPUB; USOCR; EPO; JPO; DERWENT	2004/12/02 10:10		